

Speech network

BA6566 / BA6566F / BA6566FP

The BA6566, BA6566F, and BA6566FP are speech network ICs which possess the basic functions required for handset communications. In addition to amplifying signals from a transmitter and sending them to a telephone line, they amplify only reception signals from a telephone line and drive the receiver. They also compensate for fluctuation in the volume at which signals are transmitted and received, caused by the length of the telephone line (AGC).

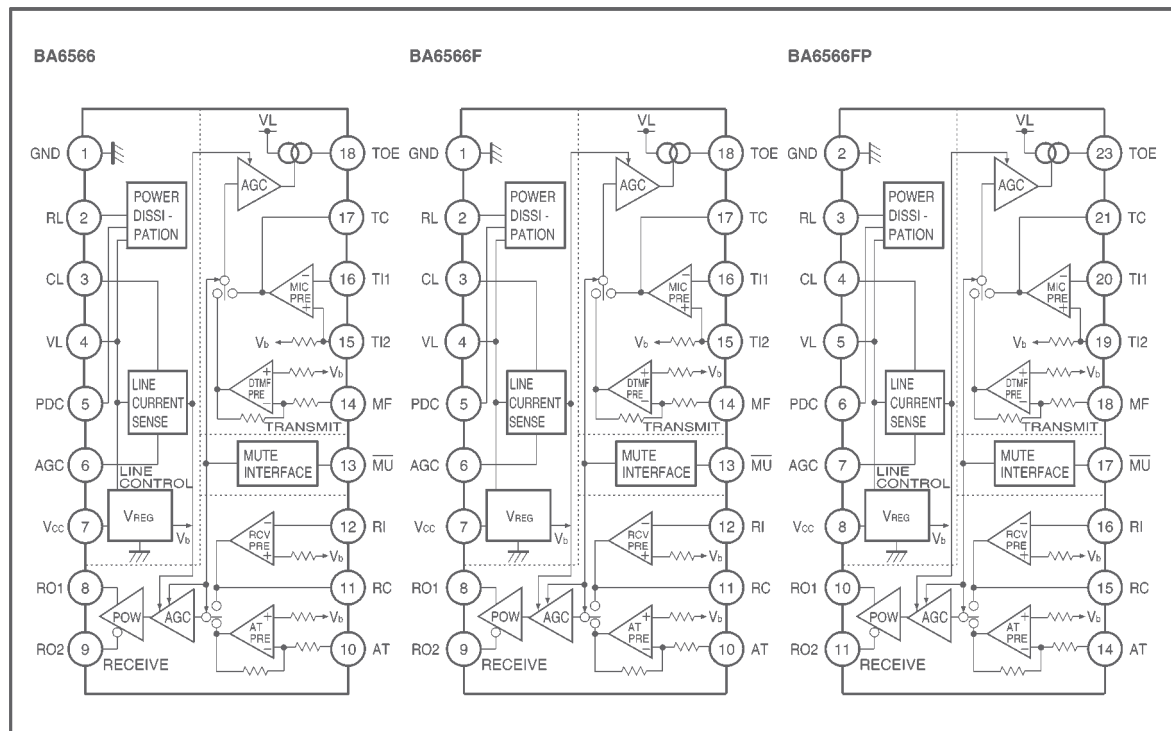
●Applications

Telephones and telephone equipment

●Features

- 1) Can accommodate both dynamic and piezoelectric receivers, simply by changing the circuit constant for a wide dynamic reception range.
- 2) Automatic gain control (AGC) is used, based on the transmission and reception telephone line current, for easier compliance with communications standards.
- 3) Erroneous operation caused by high-frequency electrical wave interference is minimized.
- 4) An HSOP package is used, eliminating the need for an attached transistor to dissipate heat. This means that a common circuit can be shared when a DIP package is used (BA6566FP).

●Block diagram



●Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Applied voltage		V _L	16.5	V
Power dissipation	BA6566	P _d	1100* ¹	mW
	BA6566F		600* ²	
	BA6566FP		1350* ³	
Operating temperature		T _{opr}	−35~+60	°C
Storage temperature		T _{stg}	−55~+125	°C
Current dissipation		I _L	125* ⁴	mA

*1 Reduced by 11 mW for each increase in Ta of 1°C over 25°C.

*2 Reduced by 6 mW for each increase in Ta of 1°C over 25°C.

*3 Reduced by 13.5 mW for each increase in Ta of 1°C over 25°C.

When mounted on 90 mm × 50 mm × 1.6 mm glass epoxy board, fins should be soldered to foil pattern.

*4 With the BA6566, Reduced by 1 mA for each increase in Ta of 1°C over 50°C.

With the BA6566F, Reduced by 1.4 mA for each increase in Ta of 1°C over 50°C.

With the BA6566FP, Reduced by 1 mA for each increase in Ta of 1°C over 50°C.

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions				Measurement circuit
						I _L (mA)	AGC	Mute	f=1kHz	
Line voltage (5)	V _L (5)	—	2.0	—	V	5	—	—	—	Fig.2
Line voltage (20)	V _L (20)	2.5	3.5	5.0	V	20	—	—	—	Fig.2
Line voltage (30)	V _L (30)	3.0	4.0	5.4	V	30	—	—	—	Fig.2
Line voltage (90)	V _L (90)	5.2	7.0	9.5	V	90	—	—	—	Fig.2
Mute input low level voltage	V _{IL}	0.1	0.18	0.25	V	20~90	—	—	—	Fig.2
Mute input low level current	I _{IL}	25	35	45	μA	20~90	—	—	—	Fig.2
Transmit gain 1 (20 - 90)	G _{T1} (20 - 90)	37	41	44	dB	20~90	OFF	OFF	V _{IN} =-50dBV	Fig.3
Transmit gain 1 (30 - 90)	G _{T1} (30 - 90)	38	41	44	dB	30~90	OFF	OFF	V _{IN} =-50dBV	Fig.3
Transmit gain 2 (20)	G _{T2} (20)	38	41	45	dB	20	ON	OFF	V _{IN} =-50dBV	Fig.3
Transmit gain 2 (30)	G _{T2} (30)	38	41	44	dB	30	ON	OFF	V _{IN} =-50dBV	Fig.3
Transmit gain 2 (90)	G _{T2} (90)	34.5	37.5	40.5	dB	90	ON	OFF	V _{IN} =-50dBV	Fig.3
Transmit distortion attenuation	D _T	—	-46	-20	dB	20~90	—	OFF	V _{IN} =-50dBV	Fig.3
Transmit noise level	N _T	—	-68	-55	dBV	20~90	—	OFF	BPF=400Hz ~30kHz	Fig.3
Maximum transmit output level (20 - 90)	O _T (20 - 90)	-2	3	—	dBV	20~90	—	OFF	Dist=-20dB	Fig.3
Maximum transmit output level (30 - 90)	O _T (30 - 90)	0	3	—	dBV	30~90	—	OFF	Dist=-20dB	Fig.3
Receive gain 1 (20 - 90)	G _{R1} (20 - 90)	-13	-10	-7	dB	20~90	OFF	OFF	S _i =1 V _{IN} =-20dBV	Fig.4
Receive gain 1 (20)	G _{R1} (20)	-13	-10	-7	dB	20	ON	OFF	S _i =1 V _{IN} =-20dBV	Fig.4
Receive gain 1 (30)	G _{R1} (30)	-13	-10	-7	dB	30	ON	OFF	S _i =1 V _{IN} =-20dBV	Fig.4
Receive gain 1 (90)	G _{R1} (90)	-16.5	-13.5	-10.5	dB	90	ON	OFF	S _i =1 V _{IN} =-20dBV	Fig.4
Receive distortion attenuation 1	D _{R1}	—	-46	-20	dB	20~90	—	OFF	S _i =1 V _{IN} =-20dBV	Fig.4
Receive noise level 1	N _{R1}	—	-70	-60	dBV	20~90	—	OFF	BPF=400Hz ~30kHz	Fig.4
Maximum receive output level 1 (20 - 90)	O _{R1} (20 - 90)	-15	-7	—	dBV	20~90	—	OFF	Dist=-20dB	Fig.4
Maximum receive output level 1 (30 - 90)	O _{R1} (30 - 90)	-11	-7	—	dBV	30~90	—	OFF	Dist=-20dB	Fig.4
Receive gain 2 (20 - 90)	G _{R2} (20 - 90)	5	8	11	dB	20~90	OFF	OFF	S _i =2 V _{IN} =-20dBV	Fig.4
Receive gain 2 (20)	G _{R2} (20)	5	8	11	dB	20	ON	OFF	S _i =2 V _{IN} =-20dBV	Fig.4

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions				Measurement circuit
						I _L (mA)	AGC	Mute	f=1kHz	
Receive gain 2 (30)	G _{R2} (30)	5	8	11	dB	30	ON	OFF	S ₁ =2 V _{IN} =-20dBV	Fig.4
Receive gain 2 (90)	G _{R2} (90)	1.5	4.5	7.5	dB	90	ON	OFF	S ₁ =2 V _{IN} =-20dBV	Fig.4
Receive distortion attenuation 2	D _{R2}	—	-46	-20	dB	20~90	—	OFF	S ₁ =2 V _{IN} =-20dBV	Fig.4
Receive noise level (20 - 90)	N _{R2} (20 - 90)	—	-66	-50	dBV	20~90	—	OFF	BPF=400Hz ~30kHz	Fig.4
Receive noise level 2 (30 - 90)	N _{R2} (30 - 90)	—	-66	-55	dBV	30~90	—	OFF	BPF=400Hz ~30kHz	Fig.4
Maximum receive output level 2 (20 - 90)	O _{R2} (20 - 90)	1	7	—	dBV	20~90	—	OFF	Dist=-20dB	Fig.4
Maximum receive output level 2 (30 - 90)	O _{R2} (30 - 90)	3	7	—	dBV	30~90	—	OFF	Dist=-20dB	Fig.4
DTMF gain 1 (20 - 90)	G _{D1} (20 - 90)	30.5	33.5	36.5	dB	20~90	OFF	ON	V _{IN} =-40dBV	Fig.5
DTMF gain 2 (20)	G _{D1} (20)	30	33	36	dB	20	ON	ON	V _{IN} =-40dBV	Fig.5
DTMF gain 2 (30)	G _{D2} (30)	30	33	36	dB	30	ON	ON	V _{IN} =-40dBV	Fig.5
DTMF gain 2 (90)	G _{D2} (90)	27	30	33	dB	90	ON	ON	V _{IN} =-40dBV	Fig.5
DTMF distortion attenuation	D _D	—	-41	-28	dB	20~90	—	ON	V _{IN} =-40dBV	Fig.5
DTMF noise level (20 - 90)	N _D	—	-64	-55	dBV	20~90	—	ON	BPF=400Hz ~30kHz	Fig.5
Maximum DTMF output level (20 - 90)	O _D (20 - 90)	-4.5	-0.5	—	dBV	20~90	—	ON	Dist=-28dB	Fig.5
Maximum DTMF output level (30 - 90)	O _D (30 - 90)	-3.5	-0.5	—	dBV	30~90	—	ON	Dist=-28dB	Fig.5
AT gain 1	G _{A1}	23.5	26.5	29.5	dB	20~90	—	ON	S ₁ =1 V _{IN} =-40dBV	Fig.6
AT gain 2	G _{A2}	26.5	29.5	32.5	dB	20~90	—	ON	S ₁ =2 V _{IN} =-40dBV	Fig.6
AC impedance	Z _{TEL}	450	565	750	Ω	20~90	—	—	V _{IN} =-20dBV	Fig.7
V _{CC} pin voltage	V _{CCR}	1.15	1.27	—	V	20	—	—	S ₃ =ON	Fig.2

[illegible]**ROHM**

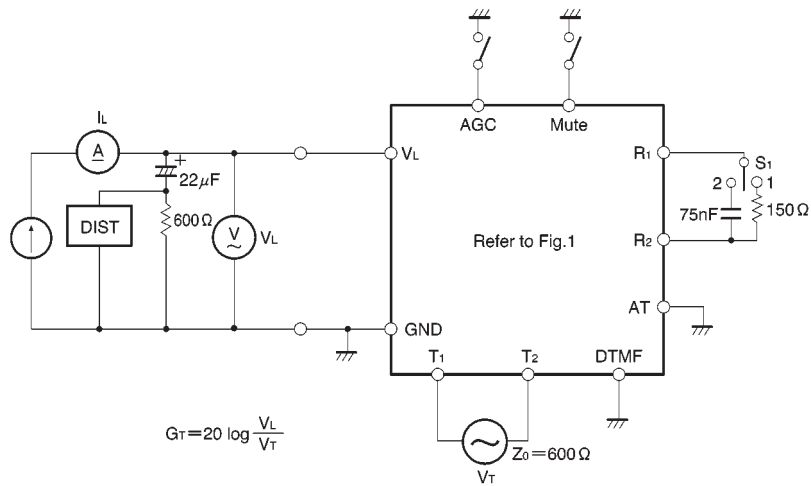


Fig. 3

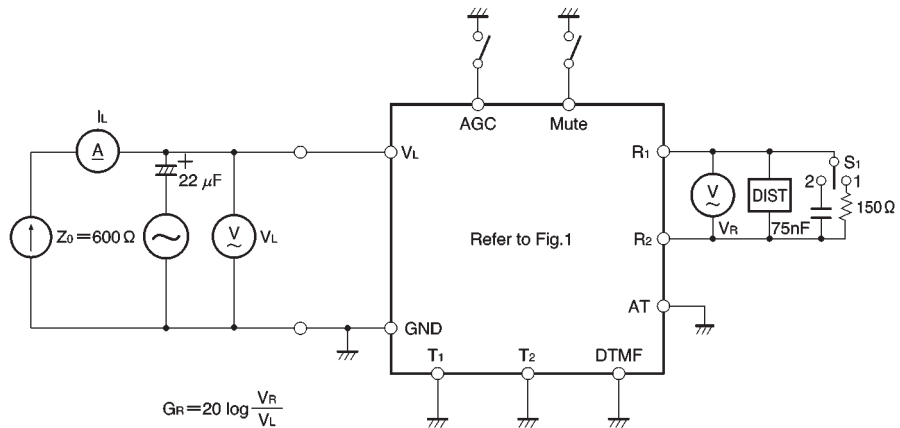


Fig. 4

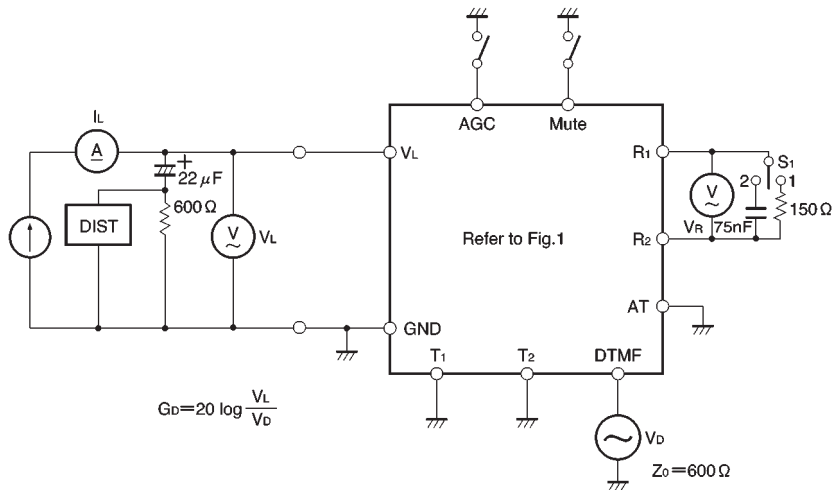


Fig. 5

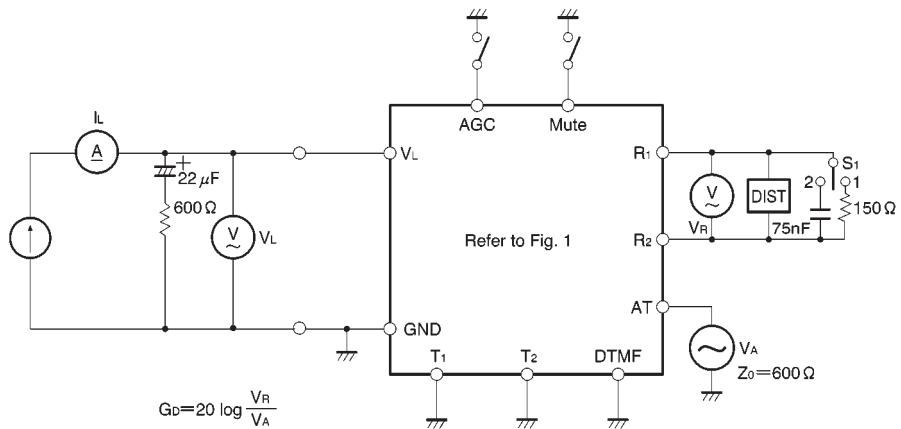


Fig. 6

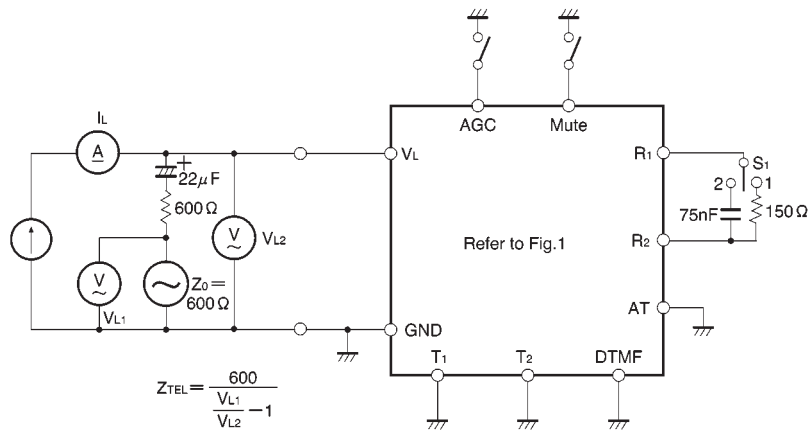
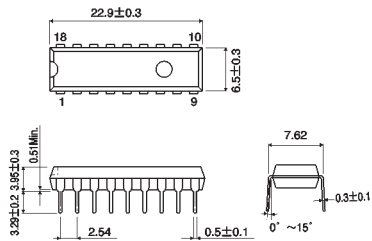


Fig. 7

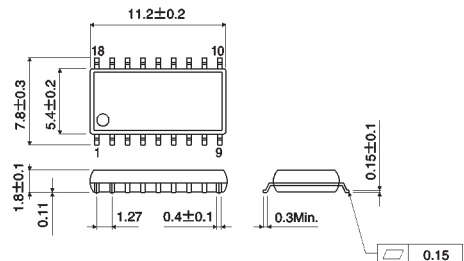
● External dimensions (Units: mm)

BA6566



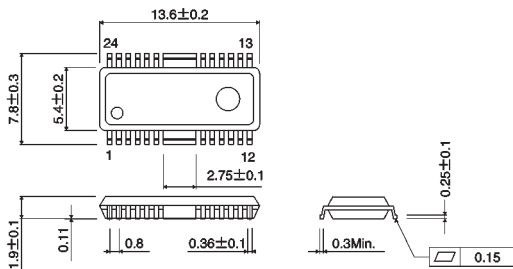
DIP18

BA6566F



SOP18

BA6566FP



HSOP24



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.